DATA SHEET

AC03DGM, AC03FGM

3 A MOLD TRIAC

The AC03EGM and AC03FGM are fully diffused mold TRIACs with an effective on-current of 3 A. The repeat peak off-voltages are 400 V and 600 V.

FEATURES

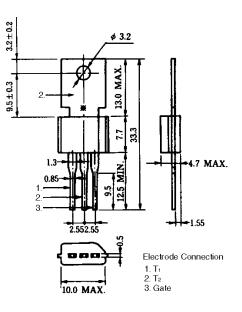
NEC

- Gate trigger current (mode I, III, and IV) at 12 mA or less is guaranteed.
- This transistor features a small and lightweight package and is easy to handle even on the mounting surface due to its TO-202AA dimensions. Processing of lead wires and heatsink (tablet) using jigs is also possible.
- High degrees-of-freedom applications design is available due to high gate trigger sensitivity and small hold current distribution.
- Employs flame-retardant epoxy resin (UL94V-0).

APPLICATIONS

Noncontact switches of motor speed control, heater temperature control, lamp light control

PACKAGE DRAWING (UNIT: mm)



*Tc test bench-mark

Standard weight: 1.4 g

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	AC03DGM	AC03FGM	Unit	Remarks	
Non-repetitive peak off-state voltage	VDSM	500	700	V	-	
Repetitive peak off-voltage	VDRM	400	600	V	-	
Effective on-state current	IT(RMS)	3 (Tc =	= 92°C)	A	Refer to Figures 11 and 12.	
Surge on-state current	Ітѕм	30 (50 Hz 33 (60 Hz	,	A	Refer to Figure 2.	
Fusing current	<i>f</i> i⊤²dt	4.0 (1 ms ≤	≦ t ≤ 10 ms)	A ² s	-	
Critical rate of rise of on-state current	dl⊤/dt	4	0	A/μs	-	
Peak gate power dissipation	Рсм	3 (f ≥ 50 Hz,	Duty ≤ 10 %)	W	-	
Average gate power dissipation	PG(AV)	0.3		W	-	
Peak gate current	Ідм	±0.5 (f ≥ 50 Hz	z, Duty ≤ 10 %)	А	-	
Junction temperature	Tj	-40 to	+125	°C	-	
Storage temperature	Tstg	–55 tc	9 +150	°C	_	

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ELECTRICAL CHARACTERISTICS (Tj = 25°C, RGK = 1 k Ω)

Parameter		Symbol	Conditions		MIN.	TYP.	MAX.	Unit	Remarks
Repeat peak off-current		Idrm		$T_j = 25^{\circ}C$	-	_	100	μA	
			Vdm = Vdrm	$T_j = 125^{\circ}C$	-	-	1	mA	_
On-state voltage		Vтм	Iтм = 5 A		-	_	1.8	v	Refer to Figure 1.
Gate trigger current	Mode I			T2 +, G+	-	-	12	mA	Refer to Figure 4.
	II	Іст	V _{DM} = 12 V R _L = 30 Ω	T2 -, G+	-		-		
	Ш			T2 –, G–	-	I	12		
	IV			T2 +, G-	-	I	12		
Gate trigger voltage	Mode I	VGT	$V_{\text{DM}} = 12 \text{ V}$ $R_{\text{L}} = 30 \ \Omega$	T2 +, G+	-	-	1.5	V	Refer to Figure 4.
	П			T2 –, G+	-	-	-		
	Ш	VGI		T2, G	-	-	1.5		
	IV			T2 +, G-	-	-	1.5		
Gate non-trigger voltage		Vgd	$T_j = 125^{\circ}C, V_{DM} = \frac{1}{2}V_{DRM}$		0.2	-	_	v	_
Hold current		Ін	Vdm = 24 V, Itm = 5 A		-	10	-	mA	-
Critical rate of rise of off- state voltage		dv/dt	$T_j = 125^{\circ}C, V_{DM} = \frac{2}{3}V_{DRM}$		-	100	_	V/µs	_
Commutating critical rate of rise of off-state voltage		(dv/dt)c	$T_j = 125^{\circ}C$ $(di\tau/dt)c = -1.6 \text{ A/ms}$ $V_D = 400 \text{ V}$		5	_	-	V/µs	_
Thermal resistance*		Rth(j-c)	Junction-to-cas	-	-	10	°C/W	Refer to	
		Rth(j–a)	Junction-to-am	-	-	75	°C/W	Figure 13.	

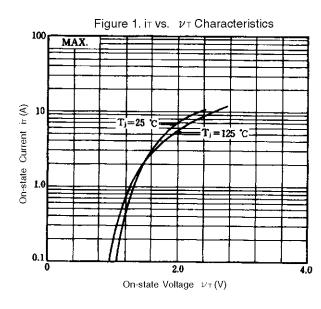
 * The thermal resistance at 50 Hz and 60 Hz sine wave current, which is shown on the following expression:

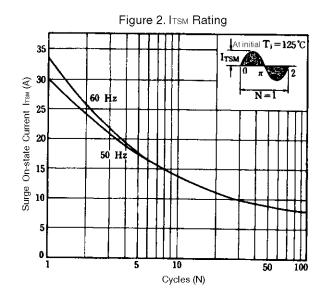
 $R_{th(j-c)} = \frac{T_{j(max)} - T_C}{P_{T}(AV)}$

 $T_{j(max)} \hspace{0.1 cm} : \hspace{0.1 cm} Maximum \hspace{0.1 cm} junction \hspace{0.1 cm} temperature$

Tc :Case temperature

 $P_{\mathsf{T}(\mathsf{AV})}$: Average on-dissipation





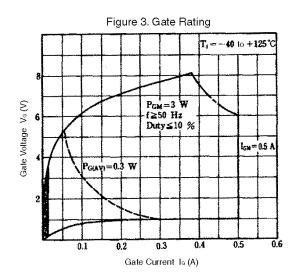
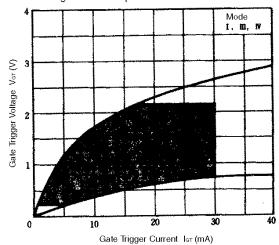
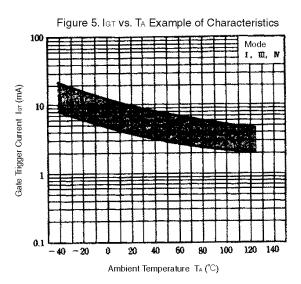
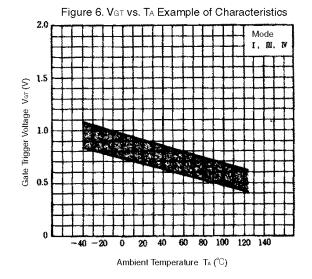


Figure 4. Example of Gate Characteristics







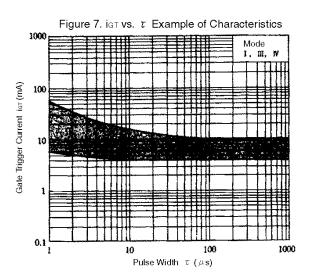
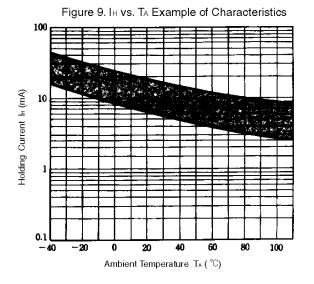
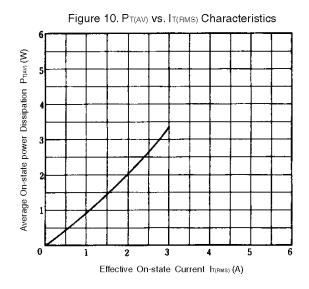
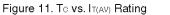
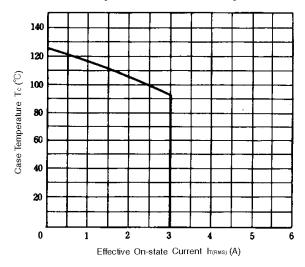


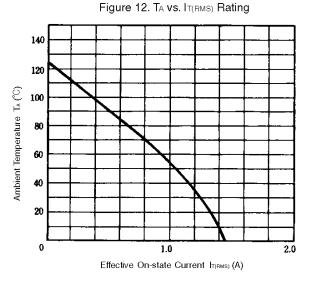
Figure 8. v at vs. r Example of Characteristics



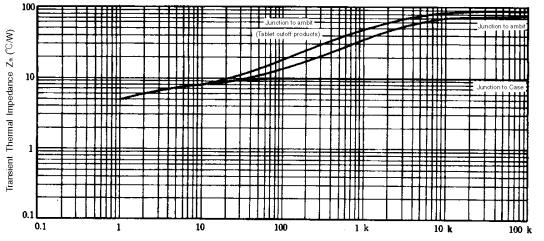












Cycles (50 Hz)

[MEMO]

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